

DESCRIPTION

The BAS16TW is available in SC-88 Package.

FEATURES

- Fast Switching Speed
- Ultra-Small Surface Mount Package
- For General Purpose Switching Applications
- High Conductance
- Also Available in Lead Free Version
- Available in SC-88 Package

ORDERING INFORMATION

Package Type	Part Number			
SC-88	BAS16TW			
Note	SPQ: 3,000pcs/Reel			
AiT provides all RoHS Compliant Products				

PIN DESCRIPTION





ABSOLUTE MAXIMUM RATINGS

T _A = 25°C, unless otherwise specified	
V _{RM} , Non-Repetitive Peak Reverse Voltage	100V
V _{RRM} , Peak Repetitive Reverse Voltage	75V
V _{RWM} , Working Peak Reverse Voltage	75V
V _R , DC Blocking Voltage	75V
V _{R(RMS)} , RMS Reverse Voltage	53V
I _{FM} , Forward Continuous Current ^{NOTE1}	300mA
Io, Average Rectified Output Current ^{NOTE1}	150mA
IFSM, Non-Repetitive Peak Forward Surge Current	
@ t = 1.0µs	2.0A
@ t = 1.0s	1.0A
P _D , Power Dissipation ^{NOTE1}	200mW
R _{0JA} , Thermal Resistance Junction to Ambient Air ^{NOTE1}	625°C/W
T _J , T _{STG} , Operating and Storage Temperature Range	-65°C ~ +150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



ELECTRICAL CHARACTERISTICS

 $T_A = 25^{\circ}C$, unless otherwise specified

Parameter	Symbol	Conditions	Min	Max	Unit	
Reverse Breakdown VoltageNOTE2	V _{(BR)R}	I _R = 1μΑ	75	-	V	
Forward Voltage ^{NOTE2}	VF	I⊧ = 1.0mA	-	0.715		
		I _F = 10mA	-	0.855	V	
		I _F = 50mA	-	1.0		
		I⊧ = 150mA	-	1.25		
Reverse Current ^{NOTE2}	I _R	V _R = 75V	-	1.0	μA	
		V _R = 75V, T _J = 150°C	-	50		
		V _R = 25V, T _J = 150°C	-	30		
		V _R = 20V	-	25	nA	
Total Capacitance	Ст	V _R = 0V, f = 1.0MHz	-	2.0	pF	
	4	I _F = I _R = 10mA,		4.0		
Reverse Recovery Time	T rr	$I_{rr} = 0.1 \text{ x } I_{R}, R_{L} = 100\Omega$	-	4.0	ns	

NOTE1: Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch.

NOTE2: Short duration test pulse used to minimize self-heating effect.



TYPICAL CHARACTERISTICS

Figure 1. Forward Voltage



VF, FORWARD VOLTAGE (VOLTS)



Figure 2. Leakage Current

VR, REVERSE VOLTAGE (VOLTS)

Figure 3. Capacitance





PACKAGE INFORMATION

Dimension in SC-88 Package (Unit: mm)



DIM	Millimeters		Inches		
	Min	Max	Min	Max	
А	0.80	1.10	0.031	0.043	
A1	0.00	0.10	0.000	0.004	
A3	0.20REF		0.008REF		
b	0.10	0.30	0.004	0.012	
С	0.10	0.25	0.004	0.010	
D	1.80	2.20	0.070	0.086	
E	1.15	1.35	0.045	0.053	
е	0.65 BSC		0.026 BSC		
L	0.10	0.30	0.004	0.012	
HE	2.00	2.20	0.078	0.086	



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